

# Supplementary Information

## Heteroleptic enantiopure Pd(II)-complexes derived from halogen-substituted Schiff bases and 2-picollylamine: synthesis, experimental and computational characterization and investigation of the influence of chirality and halogen atoms on the anticancer activity

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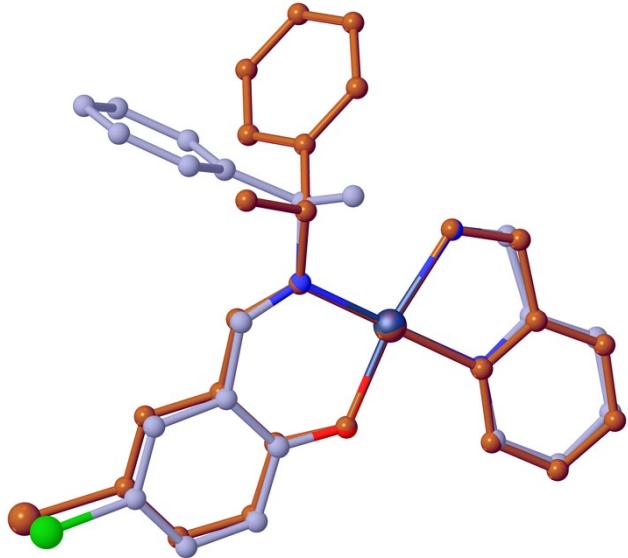
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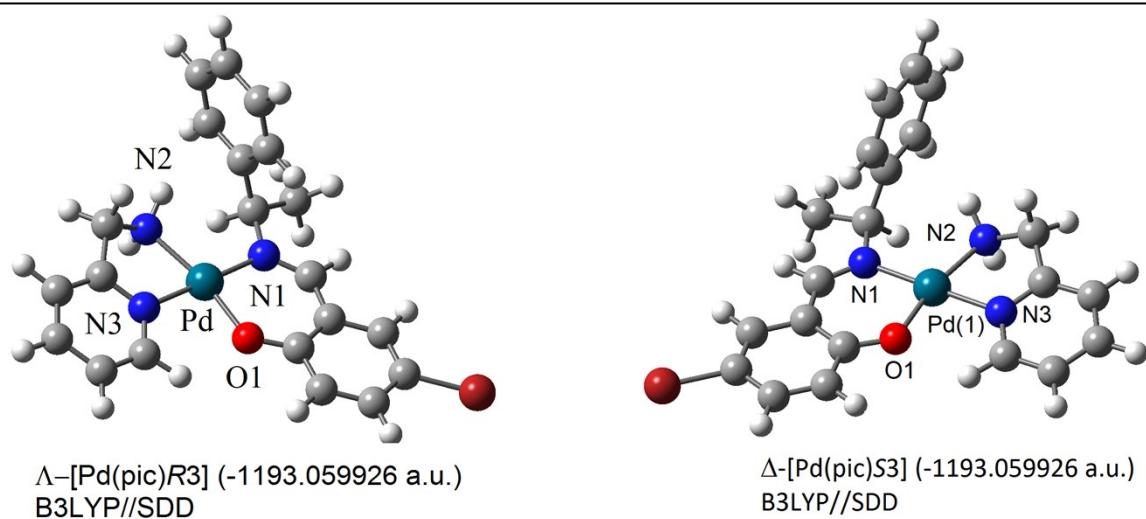
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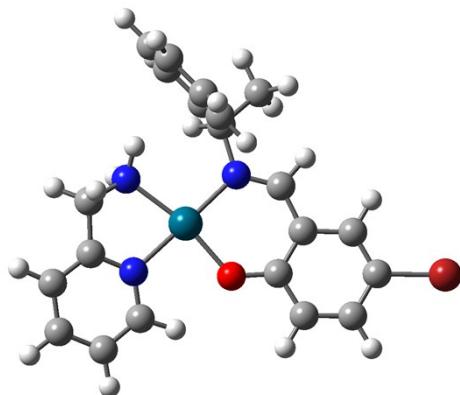
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**Fig. S1** Overlap of the cations  $[\text{Pd}(\text{pic})\text{R}3]^+$  and  $[\text{Pd}(\text{pic})\text{R}2]^+$ , showing  $[\text{Pd}(\text{pic})\text{R}3]^+$  in brown color. H atoms have been omitted for clarity.

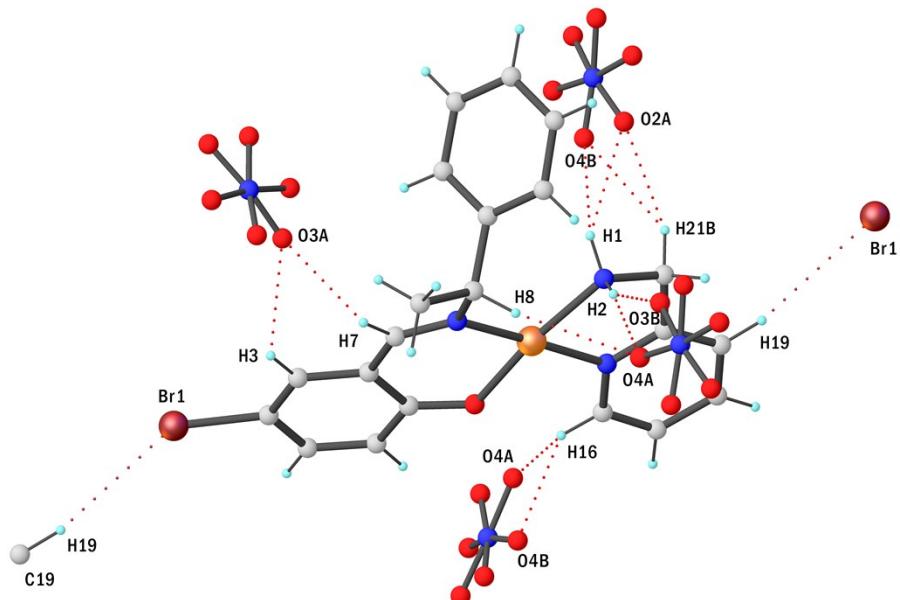




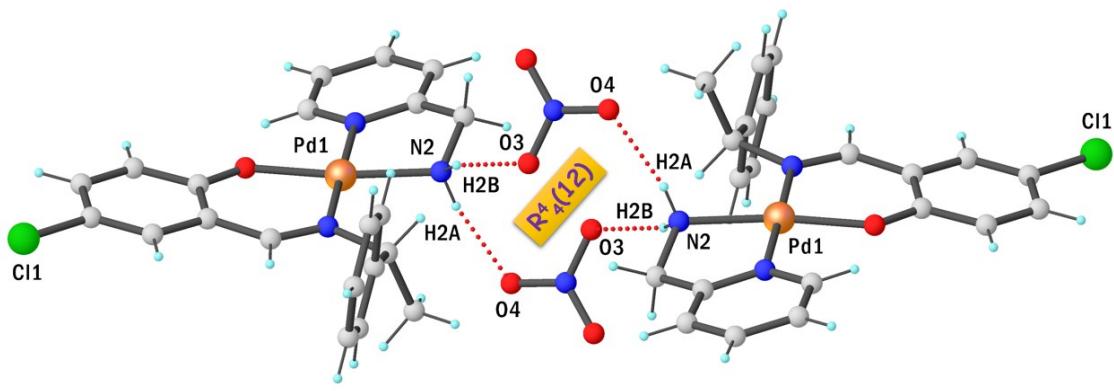
Λ-[Pd(pic)R3] (-1191.652683 a.u.)  
B3LYP//LANL2DZ

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**Fig S2** DFT optimized structures (gas phase) for the enantiomeric pair Λ-[Pd(pic)R3] and Δ-[Pd(pic)S3].



**Fig. S3** A view of intermolecular interactions in the crystal packing of [Pd(pic)R3]NO<sub>3</sub>.



**Fig. S4** Perspective view of  $R^4_4(12)$  ring in  $[Pd(\text{pic})\text{rac}2]\text{NO}_3$ .

### Hirshfeld surface analyses

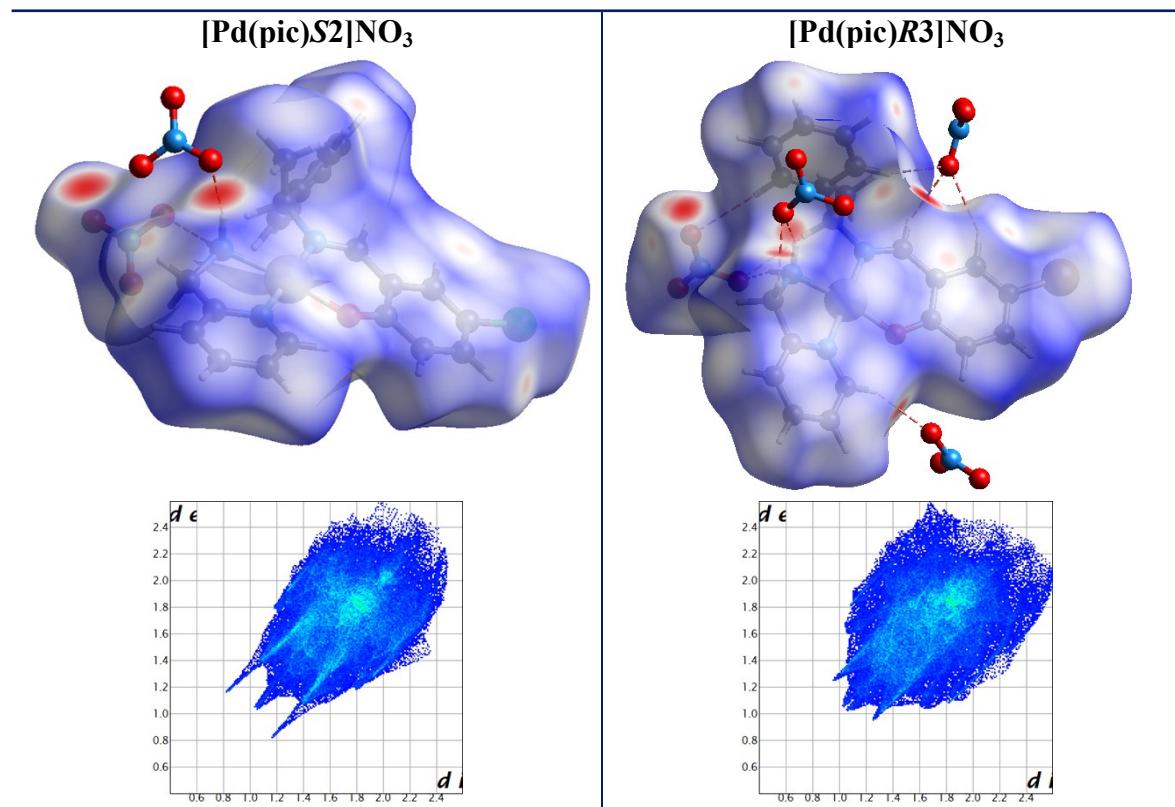
The results indicate that the highest contributions over the Hirshfeld surface are due to H atom with other atoms such as carbon (H···C), oxygen (H···O) and hydrogen (H···H) (Figs. S5 and S6). These three kind of contacts (H···H, H···C and O···H) overall are 74.8% and 72.8% of the total Hirshfeld surface area in  $[Pd(\text{pic})S2]\text{NO}_3$  and  $[Pd(\text{pic})R3]\text{NO}_3$ , respectively (Fig. S6). Between H···H, H···C and O···H interactions, FPs indicates that most of the contributions over the Hirshfeld surface are due to H···H contact (37.2 and 39.6% for  $[Pd(\text{pic})S2]\text{NO}_3$  and  $[Pd(\text{pic})R3]\text{NO}_3$ , respectively) as the molecular surface is comprised of H atoms (Fig. S6). Large number of H-atoms over surface supported the C–H contact to be the third one after O···H interaction having 15.4 and 12.8% for  $[Pd(\text{pic})S2]\text{NO}_3$  and  $[Pd(\text{pic})R3]\text{NO}_3$ , respectively (Fig. S5 and S6). Also, fingerprint plots indicate that chlorine and bromide intermolecular contacts (X···X, X···C, X···H and X···N) cover nearly 13% of the whole Hirshfeld surface (Figure. S6).

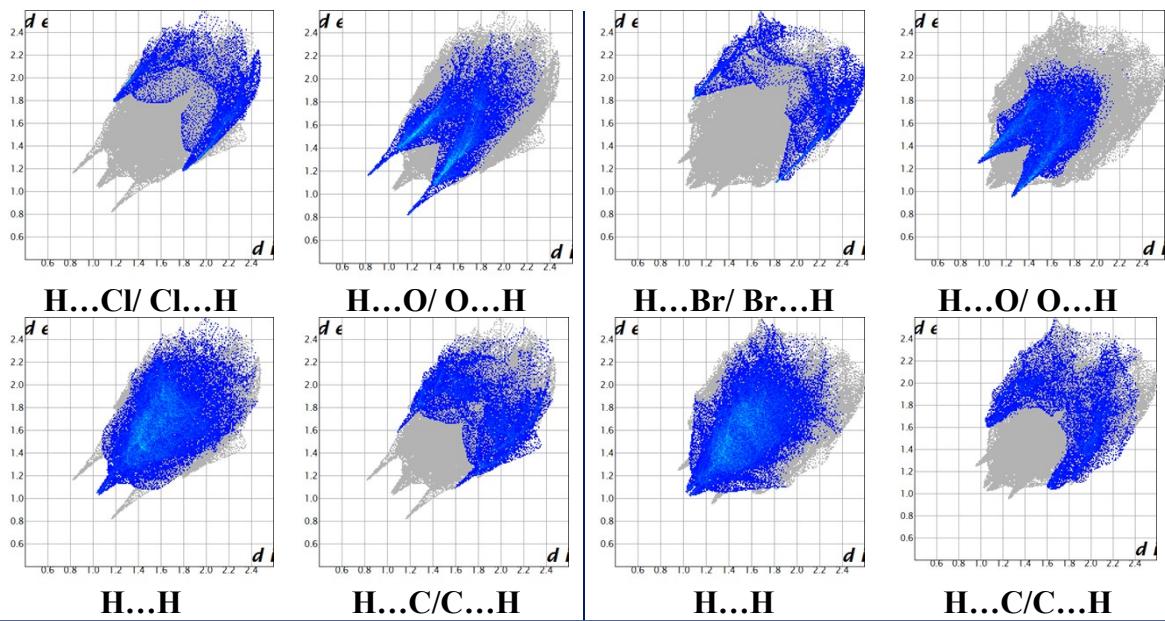
The H···H contacts are characterized by broader spikes in [Pd(pic)*R*3]NO<sub>3</sub> and sharper spikes in [Pd(pic)S2]NO<sub>3</sub> (Figs. S5). As shown in Fig. S5, the shortest H···H contacts in the fingerprint plots of both structures are at  $d_e + d_i = 2.1$  Å. Furthermore, a subtle feature, splitting in the fingerprint plots of H···H, is evident in the fingerprint plot of [Pd(pic)*R*3]NO<sub>3</sub> complex. This splitting occurs when the shortest contact is between three atoms, rather than for a direct two-atom contact.

The first principal interaction in [Pd(pic)S2]NO<sub>3</sub> and [Pd(pic)*R*3]NO<sub>3</sub>, results from classical N–H···O–NO<sub>2</sub> hydrogen bond. The dominant interactions between amine N–H and nitrate O atoms can be seen in the Hirshfeld surfaces as deep red spots (Fig. S5). In [Pd(pic)S2]NO<sub>3</sub> structure, a pair of equally deep red spots corresponds to both donor and acceptor of N–H···O hydrogen bonds. This is characteristic for the *R*<sup>4</sup>(12) dimer ring. Also, short C–H···O–NO<sub>2</sub> hydrogen bond can be seen in the Hirshfeld surfaces of [Pd(pic)*R*3]NO<sub>3</sub> as deep red spots (Fig. S5). It should be noted that we cannot see such interaction in the Hirshfeld surfaces of [Pd(pic)S2]NO<sub>3</sub>. These interactions (X–H···O–NO<sub>2</sub>; X = C or N) appear in 2D fingerprint plots as a pair of symmetric spikes extending towards the bottom left (the upper spike corresponds to the donor spike, the lower one is the acceptor spike) with  $d_i + d_e = 2.2$  and 1.95 Å for [Pd(pic)S2]NO<sub>3</sub> and [Pd(pic)*R*3]NO<sub>3</sub>, respectively.

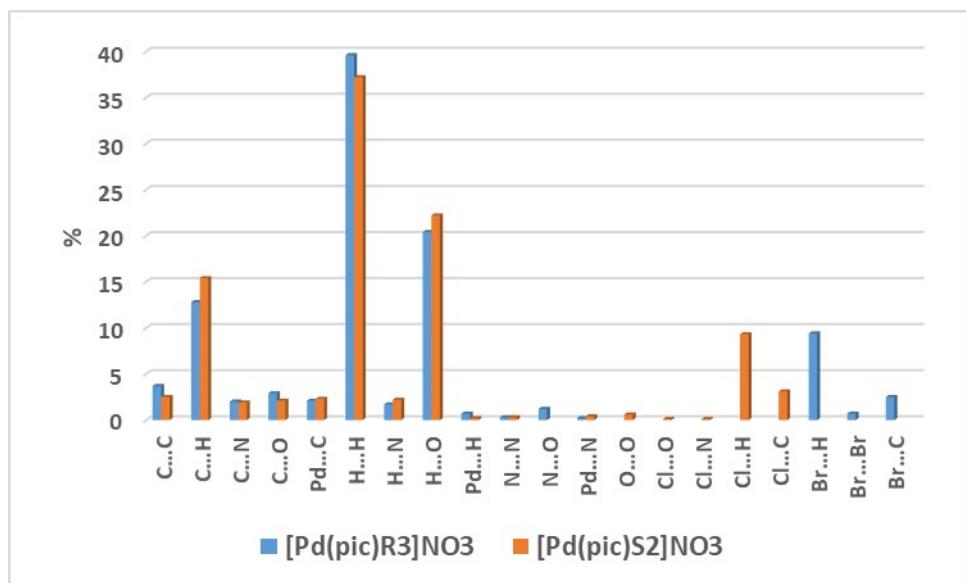
Apart from the hydrogen bonding contacts, the structure of both complexes is stabilized through a C–H···π interaction that is visible on the  $d_e$  surface as well as in the fingerprint plot (Figs. S5 and S7). The ‘bright-orange’ spot and consequently a large depression on the  $d_e$  surface above the π–cloud of the aryl ring indicates the existence of a C–H···π interaction (Figs. S5 and S7). Moreover, these interactions manifest as two weak spikes (or pair of ‘wings’) besides H···Cl interactions in the fingerprint plot of [Pd(pic)S2]NO<sub>3</sub>, while they are visible as two partly flat

spikes in the plot of  $[\text{Pd(pic)R3}]\text{NO}_3$ , where the left wing region ( $d_i < d_e$ ) correspond to the points on the surface around the C–H donor and the right wing region ( $d_e < d_i$ ) corresponds to the points surface as well as in the fingerprint plot. The interaction of the hydrogen with the halogen atom (H···Cl (or Br)) comprises a nearly high share of the Hirshfeld surface (~ 9% in both structures) and appear as wings on the top left (H...halogen) and bottom right (halogen···H) of the 2D fingerprint plots (Figs. S5 and S6). These contacts are due to C–H···halogen intermolecular interactions.  $\pi$ -stacking interactions (C···C contacts) appear in the central region of the plots and they comprise area fractions of 2.5% and 3.7% in  $[\text{Pd(pic)S2}]\text{NO}_3$  and  $[\text{Pd(pic)R3}]\text{NO}_3$  complexes, respectively.

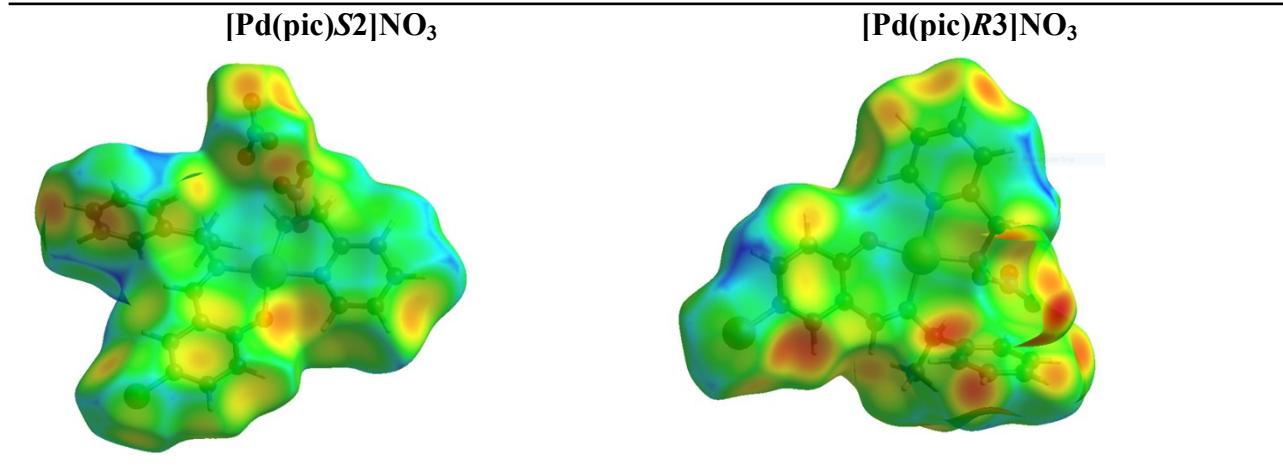




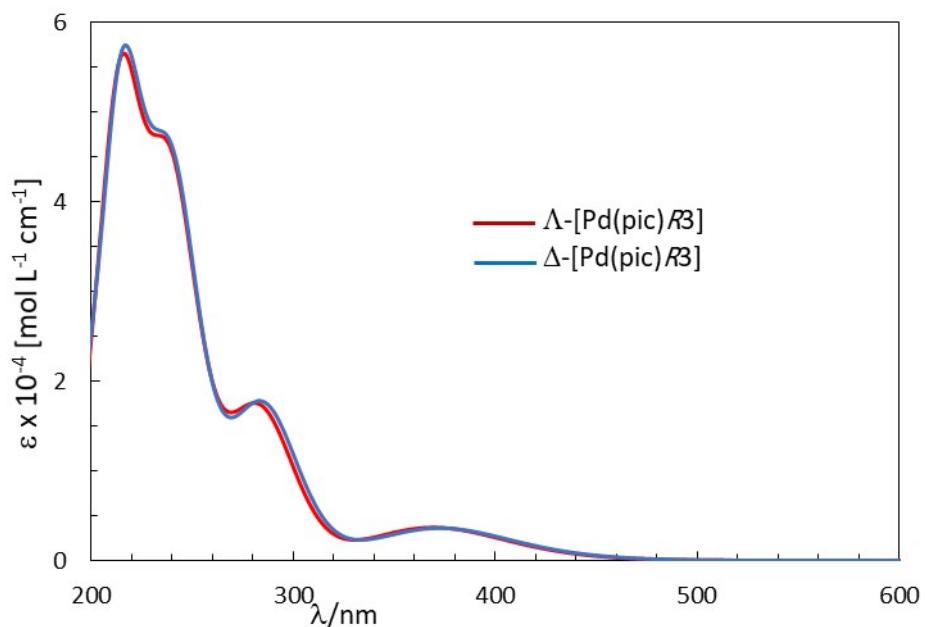
**Fig. S5** The graphical illustration of Hirshfeld surfaces with  $d_{\text{norm}}$  properties and two-dimensional fingerprint plots for  $[\text{Pd}(\text{pic})\text{S2}]\text{NO}_3$  and  $[\text{Pd}(\text{pic})\text{R3}]\text{NO}_3$ . The strongest intermolecular contacts are shown in red color, while weak contacts as blue color. The  $d_e$  (y-axis) and  $d_i$  (x-axis) values are the closest external and internal distances ( $\text{\AA}$ ) from given points on the Hirshfeld surfaces contacts.



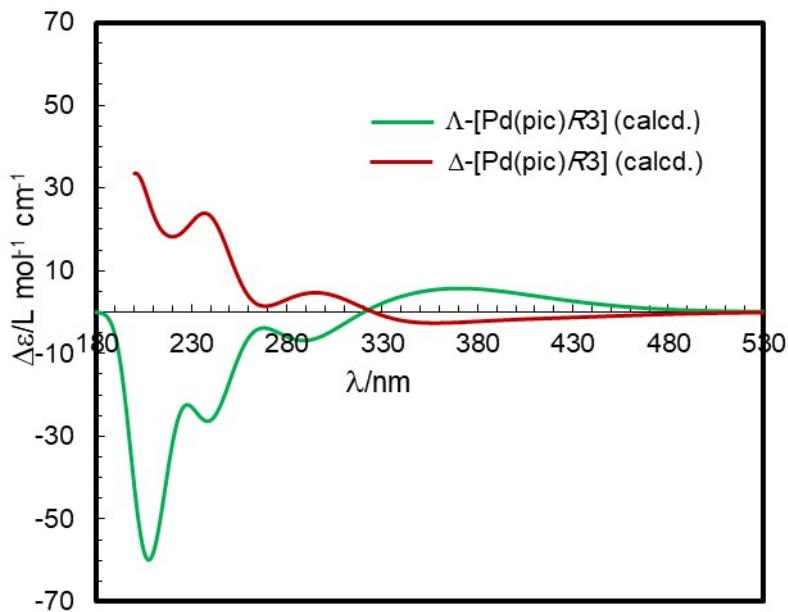
**Fig. S6** Relative contributions to the Hirshfeld surfaces area for different intermolecular contacts in  $[\text{Pd}(\text{pic})\text{S2}]\text{NO}_3$  and  $[\text{Pd}(\text{pic})\text{R3}]\text{NO}_3$ .



**Fig. S7** Hirshfeld surface of  $[\text{Pd(pic)}S2]\text{NO}_3$  and  $[\text{Pd(pic)}R3]\text{NO}_3$  mapped with  $d_e$



**Fig. S8** Calculated UV-Vis. spectra for the diastereomeric pair  $[\Lambda\text{-Pd(pic)}R3]$  and  $[\Delta\text{-Pd(pic)}R3]$ , calculated at B3LYP/SDD with PCM in dichloromethane (Gaussian band shape with exponential half-width,  $\sigma = 0.33$  eV).



**Fig. S9** Calculated ECD spectra for the diastereomeric pair  $[\Lambda\text{-Pd(pic)R3}]$  and  $[\Delta\text{-Pd(pic)R3}]$ , calculated at B3LYP/SDD with PCM in dichloromethane (Gaussian band shape with exponential half-width,  $\sigma = 0.33 \text{ eV}$ ).

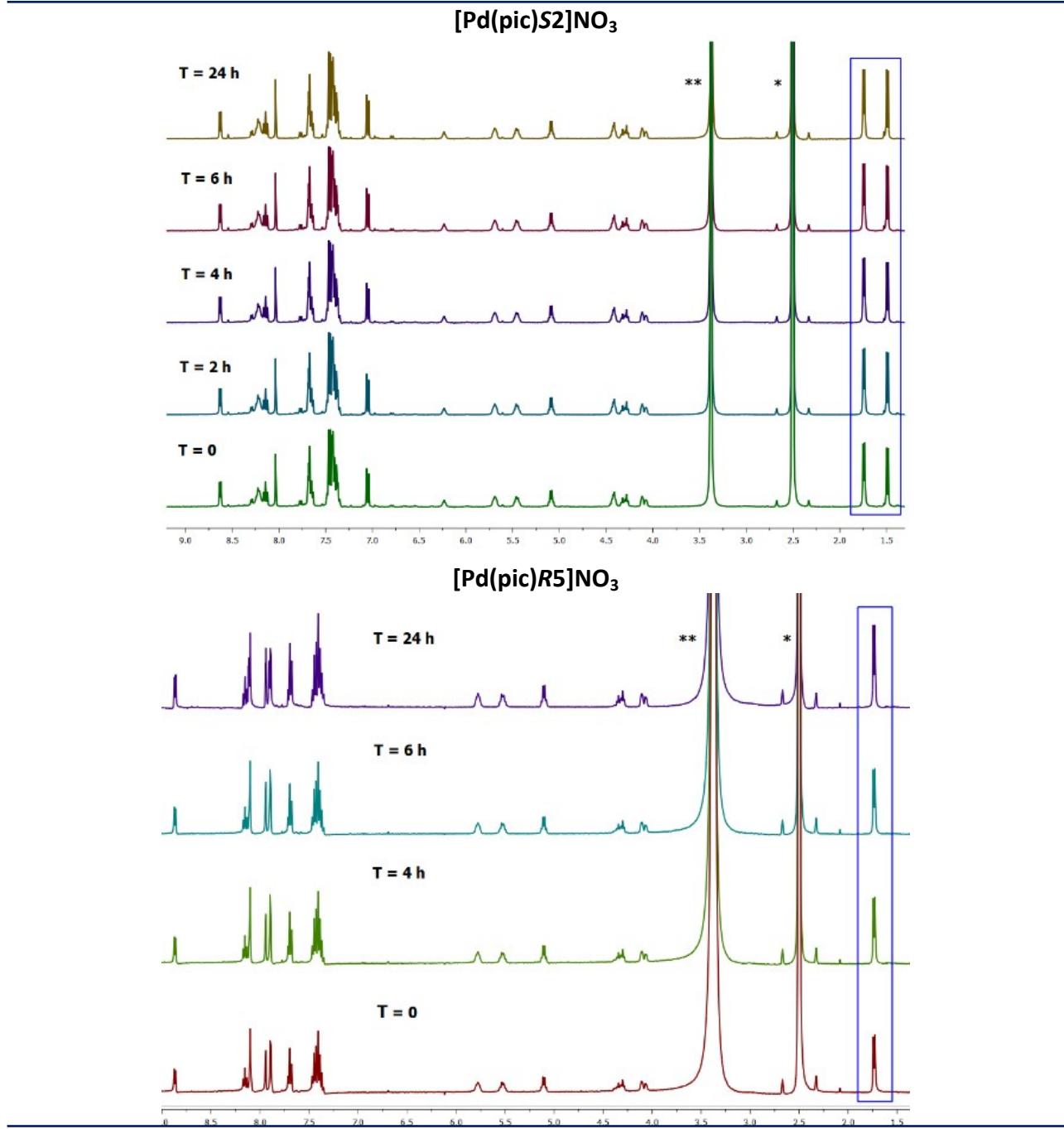
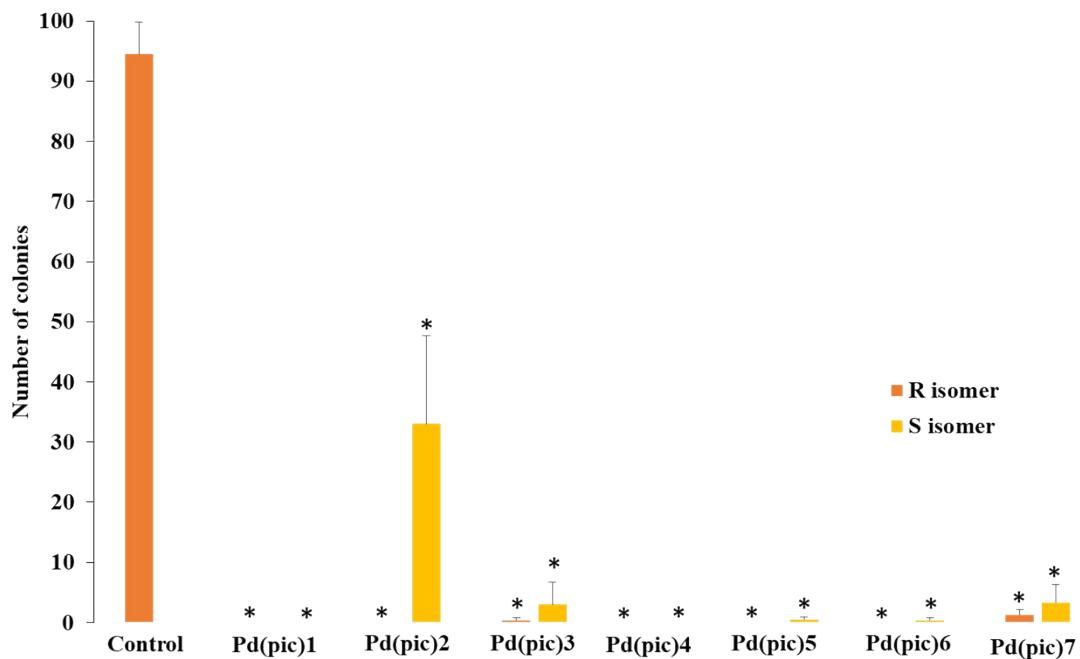


Fig S10. VT <sup>1</sup>H NMR of [Pd(pic)S2]NO<sub>3</sub> (up) and [Pd(pic)R5]NO<sub>3</sub> (down) in DMSO-*d*<sub>6</sub> solution. The hydrogen of the methyl group is indicated in the rectangular box. (\* peak for dmso-*d*<sub>6</sub> and \*\* peak for water in dmso-*d*<sub>6</sub>).



**Fig. S11** Colony formation assay of MDA-MB-231 cell line after exposure with the Pd(II) compounds. Analysis of the clonogenic ability, after 24 h of incubation with IC<sub>50</sub>. Values represent mean  $\pm$  S.D. of at least two independent experiments. Statistical analysis was performed by one-way ANOVA with Dunnett's multiple comparisons test. \*P  $\leq$  0.0001 compared with control.

**Table S1** Classical and non-classical hydrogen bonds for  $[\text{Pd}(\text{pic})R3]\text{NO}_3$  and  $[\text{Pd}(\text{pic})\text{rac}2]\text{NO}_3$ .

	D-H...A	d(D-H)	d(H...A)	d(D...A)	$\angle(\text{DHA})$
[ $\text{Pd}(\text{pic})R3]\text{NO}_3$					
C(3)—H(3)...O(3A) <sup>#1</sup>	0.95	2.62	3.333(5)	132.0	
C(7)—H(7)...O(3A) <sup>#1</sup>	0.95	2.32	3.034(5)	131.8	
C(8)—H(8)...O(4A) <sup>#2</sup>	1.00	2.63	3.599(6)	163.7	
C(16)—H(16)...O(1)	0.95	2.25	2.815(3)	117.4	
C(16)—H(16)...O(4A) <sup>#3</sup>	0.95	2.41	3.096(6)	128.4	
C(16)—H(16)...O(4B) <sup>#3</sup>	0.95	2.56	3.325(16)	138.2	
C(19)—H(19)...Br(1) <sup>#4</sup>	0.95	3.05	3.977(3)	166.4	
C(21)—H(21B)...O(2A) <sup>#5</sup>	0.99	2.41	3.139(7)	129.6	
C(21)—H(21B)...O(4B) <sup>#5</sup>	0.99	2.44	3.138(13)	126.9	
N(2)—H(2)...O(4A) <sup>#2</sup>	0.80	2.13	2.920(6)	166.4	
N(2)—H(2)...O(3B) <sup>#2</sup>	0.80	2.17	2.932(10)	159.4	
N(2)—H(1)...O(2A) <sup>#5</sup>	0.90	2.44	3.175(7)	139.1	
N(2)—H(1)...O(4B) <sup>#5</sup>	0.90	2.25	2.997(12)	140.0	
[ $\text{Pd}(\text{pic})\text{rac}2]\text{NO}_3$					
N(2)—H(2A)...O(4)	0.83	2.15	2.9776(1)	169	
N(2)—H(2B)...O(3)	0.87	2.11	2.9317(1)	156	
C(8)—H(8)...O(3)	0.98	2.48	3.4179(1)	161	
C(8)—H(8)...N(2)	0.98	2.60	3.1291(1)	114 (Intra)	
C(16)—H(16)...O(1)	0.93	2.34	2.8719(1)	116 (Intra)	
C(16)—H(16)...O(2)	0.93	2.57	3.2043(1)	126	
C(21)—H(21A)...O(1)	0.97	2.56	3.3197(1)	136	

Symmetry transformations used to generate equivalent atoms: #1: -x+3/2,-y+1,z-1/2; #2: x-1/2,-y+1/2,-z+1; #3: x,y,z-1; #4: x,y-1,z; #5: x+1/2,-y+1/2,-z+1

**Table S2** Excited states, excitation energy (eV), wavelength (nm) and oscillator strength (f) and MOs contributions for [ $\Lambda$ - $\text{Pd}(\text{pic})R3$ ], calculated at B3LYP/SDD with PCM in dichloromethane.

Excitation energies and oscillator strengths:

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Excited State 1: Singlet-A      2.8349 eV  437.35 nm  f=0.0002 <S**2>=0.000
    95 ->102      -0.22816
   100 ->102      0.65595
This state for optimization and/or second-order correction.
Total Energy, E(TD-HF/TD-KS) = -1193.34963573
Copying the excited state density for this state as the 1-particle RhoCI density.

Excited State 2: Singlet-A      3.0626 eV  404.83 nm  f=0.0168 <S**2>=0.000
    96 ->102      0.13743
    99 ->102      0.57965
   100 ->101     -0.35011

Excited State 3: Singlet-A      3.3208 eV  373.35 nm  f=0.0513 <S**2>=0.000
    99 ->102      0.33486
   100 ->101     0.60119

Excited State 4: Singlet-A      3.5587 eV  348.39 nm  f=0.0004 <S**2>=0.000
    93 ->102      0.22564
    94 ->102      0.26243
    97 ->102      0.49066
    98 ->102     -0.32794

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Excited State 100 ->103	5:	Singlet-A 0.69207	3.5968 eV	344.71 nm	f=0.0269	<S**2>=0.000
Excited State 89 ->102 91 ->102 92 ->102 99 ->101	6:	Singlet-A -0.15985 -0.19424 0.15686 0.60295	3.8604 eV	321.17 nm	f=0.0019	<S**2>=0.000
Excited State 89 ->102 91 ->102 92 ->102 99 ->101	7:	Singlet-A 0.33197 0.38032 -0.30726 0.31512	3.8690 eV	320.45 nm	f=0.0021	<S**2>=0.000
Excited State 90 ->102 95 ->102 100 ->102	8:	Singlet-A 0.27041 0.55894 0.24017	4.0867 eV	303.39 nm	f=0.0005	<S**2>=0.000
Excited State 96 ->103 99 ->103	9:	Singlet-A 0.11961 0.67673	4.2184 eV	293.92 nm	f=0.0016	<S**2>=0.000
Excited State 100 ->104	10:	Singlet-A 0.69760	4.2396 eV	292.45 nm	f=0.0001	<S**2>=0.000
Excited State 95 ->101 97 ->101 98 ->101 100 ->108	11:	Singlet-A -0.10103 -0.36072 0.55885 0.10057	4.3508 eV	284.97 nm	f=0.2885	<S**2>=0.000
Excited State 97 ->101 98 ->101	12:	Singlet-A 0.56462 0.38597	4.3554 eV	284.67 nm	f=0.0136	<S**2>=0.000
Excited State 97 ->102 98 ->102 99 ->102	13:	Singlet-A 0.33793 0.58817 0.10380	4.4274 eV	280.04 nm	f=0.0098	<S**2>=0.000
Excited State 95 ->101 96 ->101	14:	Singlet-A 0.16642 0.66468	4.5321 eV	273.57 nm	f=0.0011	<S**2>=0.000
Excited State 95 ->102 96 ->102 99 ->102	15:	Singlet-A -0.10972 0.66666 -0.14097	4.6249 eV	268.08 nm	f=0.0043	<S**2>=0.000
Excited State 95 ->101 96 ->101 97 ->103 98 ->103	16:	Singlet-A 0.57722 -0.17759 0.21995 -0.21429	4.6411 eV	267.15 nm	f=0.0313	<S**2>=0.000
Excited State 100 ->106 100 ->107	17:	Singlet-A -0.12215 0.67865	4.6531 eV	266.46 nm	f=0.0000	<S**2>=0.000
Excited State 95 ->101 97 ->102 97 ->103 98 ->103 100 ->108	18:	Singlet-A 0.28463 0.10010 -0.33740 0.46767 0.16175	4.7409 eV	261.52 nm	f=0.0389	<S**2>=0.000
Excited State 100 ->105	19:	Singlet-A 0.69435	4.8109 eV	257.72 nm	f=0.0048	<S**2>=0.000

Excited State	20:	Singlet-A	4.8170 eV	257.39 nm	f=0.0114	<S**2>=0.000
	93 ->102	0.12990				
	94 ->102	0.16174				
	97 ->102	-0.17055				
	97 ->103	0.45723				
	98 ->103	0.44114				
Excited State	21:	Singlet-A	4.8396 eV	256.19 nm	f=0.0068	<S**2>=0.000
	93 ->102	0.33033				
	94 ->102	0.42639				
	97 ->102	-0.27241				
	97 ->103	-0.27354				
	98 ->102	0.12680				
Excited State	22:	Singlet-A	4.8797 eV	254.08 nm	f=0.0029	<S**2>=0.000
	91 ->101	-0.44049				
	92 ->101	0.44727				
	93 ->101	0.12302				
	94 ->101	-0.23913				
Excited State	23:	Singlet-A	4.8917 eV	253.46 nm	f=0.0010	<S**2>=0.000
	100 ->106	0.69056				
	100 ->107	0.12249				
Excited State	24:	Singlet-A	4.9454 eV	250.71 nm	f=0.0002	<S**2>=0.000
	96 ->103	-0.10096				
	96 ->104	0.10423				
	99 ->104	0.68556				
Excited State	25:	Singlet-A	4.9567 eV	250.13 nm	f=0.0433	<S**2>=0.000
	95 ->103	0.22877				
	96 ->103	0.57511				
	99 ->104	0.10572				
	100 ->108	-0.21755				
Excited State	26:	Singlet-A	4.9809 eV	248.92 nm	f=0.1092	<S**2>=0.000
	93 ->101	0.26911				
	94 ->101	0.28600				
	96 ->103	0.29208				
	100 ->108	0.44298				
Excited State	27:	Singlet-A	5.0435 eV	245.83 nm	f=0.0055	<S**2>=0.000
	90 ->103	0.10259				
	93 ->101	0.15031				
	93 ->103	-0.14828				
	95 ->103	0.57610				
	96 ->103	-0.21213				
	97 ->104	-0.12877				
Excited State	28:	Singlet-A	5.0614 eV	244.96 nm	f=0.0259	<S**2>=0.000
	92 ->102	-0.10346				
	93 ->101	0.13258				
	93 ->102	0.52165				
	94 ->102	-0.41427				
Excited State	29:	Singlet-A	5.1151 eV	242.39 nm	f=0.0083	<S**2>=0.000
	92 ->101	0.12045				
	93 ->101	-0.17647				
	93 ->103	0.22873				
	94 ->101	0.28442				
	94 ->103	-0.22857				
	94 ->104	0.12935				
	95 ->103	0.22905				
	97 ->104	0.30992				
	98 ->104	-0.22590				
Excited State	30:	Singlet-A	5.1875 eV	239.00 nm	f=0.5760	<S**2>=0.000
	93 ->101	-0.31086				
	94 ->101	-0.34687				
	97 ->101	0.12627				
	100 ->108	0.37615				

Excited State	31:	Singlet-A	5.2416 eV	236.54 nm	f=0.0004	<S**2>=0.000
	91 ->101	0.49812				
	92 ->101	0.48042				
Excited State	32:	Singlet-A	5.2540 eV	235.98 nm	f=0.0332	<S**2>=0.000
	100 ->109	0.66092				
Excited State	33:	Singlet-A	5.2739 eV	235.09 nm	f=0.0141	<S**2>=0.000
	89 ->101	0.11215				
	91 ->101	0.14927				
	92 ->101	-0.15045				
	93 ->101	0.44427				
	93 ->103	0.18487				
	94 ->101	-0.30231				
	94 ->103	-0.16754				
	97 ->104	0.19709				
	98 ->104	-0.18223				
Excited State	34:	Singlet-A	5.2984 eV	234.00 nm	f=0.0075	<S**2>=0.000
	96 ->105	0.23524				
	96 ->106	0.30115				
	97 ->105	-0.23608				
	97 ->106	0.17195				
	98 ->104	0.10585				
	98 ->105	-0.24629				
	98 ->106	0.26585				
	99 ->105	-0.25133				
	100 ->109	0.16162				
Excited State	35:	Singlet-A	5.3534 eV	231.60 nm	f=0.0047	<S**2>=0.000
	91 ->103	0.47367				
	92 ->103	-0.43153				
	94 ->103	0.15803				
Excited State	36:	Singlet-A	5.4366 eV	228.05 nm	f=0.0151	<S**2>=0.000
	90 ->101	-0.14500				
	94 ->103	-0.20111				
	97 ->104	0.22559				
	98 ->104	0.58341				
Excited State	37:	Singlet-A	5.4489 eV	227.54 nm	f=0.1044	<S**2>=0.000
	89 ->101	0.10962				
	89 ->102	-0.22719				
	90 ->101	0.44024				
	92 ->102	-0.14067				
	93 ->103	-0.29994				
	94 ->103	-0.23716				
	97 ->104	0.12900				
Excited State	38:	Singlet-A	5.4620 eV	226.99 nm	f=0.0525	<S**2>=0.000
	89 ->101	0.16609				
	90 ->101	0.33643				
	93 ->103	0.32322				
	94 ->103	0.39514				
	97 ->104	0.13771				
	98 ->104	0.16429				
Excited State	39:	Singlet-A	5.5207 eV	224.58 nm	f=0.0221	<S**2>=0.000
	88 ->104	-0.10296				
	89 ->101	0.44014				
	92 ->103	-0.10106				
	93 ->103	0.15820				
	94 ->103	-0.21031				
	97 ->104	-0.38166				
Excited State	40:	Singlet-A	5.5476 eV	223.49 nm	f=0.0107	<S**2>=0.000
	89 ->101	0.47166				
	90 ->101	-0.22102				
	93 ->103	-0.25034				
	94 ->103	0.16097				

95 ->104	-0.10802			
97 ->104	0.26808			
Excited State 41:	Singlet-A	5.5887 eV	221.85 nm	f=0.0021 <S**2>=0.000
83 ->102	0.10097			
89 ->102	-0.11631			
90 ->102	0.59520			
95 ->102	-0.29508			
Excited State 42:	Singlet-A	5.5961 eV	221.56 nm	f=0.0018 <S**2>=0.000
96 ->104	0.66359			
99 ->105	0.15377			
Excited State 43:	Singlet-A	5.6144 eV	220.83 nm	f=0.0248 <S**2>=0.000
96 ->104	-0.16440			
96 ->105	0.15383			
97 ->105	-0.10738			
98 ->105	-0.14655			
99 ->105	0.52173			
100 ->110	-0.29623			
Excited State 44:	Singlet-A	5.6168 eV	220.74 nm	f=0.0193 <S**2>=0.000
89 ->102	0.13072			
90 ->101	0.13375			
92 ->102	0.24959			
99 ->105	0.31768			
100 ->110	0.47620			
Excited State 45:	Singlet-A	5.6464 eV	219.58 nm	f=0.0393 <S**2>=0.000
91 ->102	0.42425			
92 ->102	0.47341			
100 ->110	-0.27402			
Excited State 46:	Singlet-A	5.6809 eV	218.25 nm	f=0.0307 <S**2>=0.000
96 ->106	0.15910			
99 ->106	0.66946			
Excited State 47:	Singlet-A	5.7489 eV	215.66 nm	f=0.2302 <S**2>=0.000
89 ->102	-0.18792			
90 ->101	-0.11249			
90 ->104	0.10317			
91 ->102	0.14249			
95 ->104	0.57036			
100 ->110	0.10506			
100 ->111	-0.17832			
Excited State 48:	Singlet-A	5.7755 eV	214.67 nm	f=0.2145 <S**2>=0.000
89 ->102	0.15209			
95 ->104	0.22470			
99 ->108	0.51434			
100 ->111	0.26117			
Excited State 49:	Singlet-A	5.7832 eV	214.39 nm	f=0.3134 <S**2>=0.000
89 ->102	-0.17150			
91 ->102	0.10311			
95 ->104	-0.21524			
98 ->108	-0.11011			
99 ->108	0.44783			
99 ->109	0.10266			
100 ->111	-0.34501			
Excited State 50:	Singlet-A	5.8328 eV	212.56 nm	f=0.0221 <S**2>=0.000
89 ->102	-0.21098			
91 ->102	0.13326			
97 ->105	0.19171			
98 ->105	-0.22058			
100 ->110	0.16159			
100 ->111	0.40053			
100 ->112	0.29044			
Excited State 51:	Singlet-A	5.8385 eV	212.36 nm	f=0.0076 <S**2>=0.000

94 ->107	0.10645
97 ->105	0.25185
97 ->106	0.12138
97 ->107	-0.30354
98 ->105	-0.26699
98 ->106	-0.16178
98 ->107	0.37710
100 ->112	-0.13337
 Excited State 52:	Singlet-A
97 ->105	0.35335
97 ->107	0.26549
98 ->105	-0.34142
98 ->107	-0.33167
100 ->112	-0.11143
 Excited State 53:	Singlet-A
89 ->103	0.10907
91 ->103	0.46006
92 ->103	0.50479
 Excited State 54:	Singlet-A
97 ->105	0.10713
97 ->106	-0.45840
97 ->107	-0.12203
98 ->106	0.46382
98 ->107	0.14499
 Excited State 55:	Singlet-A
89 ->102	0.12434
97 ->108	0.22823
98 ->108	-0.23800
100 ->108	0.10586
100 ->110	-0.19070
100 ->112	0.50394
 Excited State 56:	Singlet-A
87 ->101	-0.10338
88 ->102	-0.13626
89 ->103	0.57167
90 ->103	0.27220
91 ->103	-0.11419
 Excited State 57:	Singlet-A
87 ->101	0.36330
96 ->105	-0.28309
96 ->106	0.17240
97 ->105	-0.25549
97 ->106	-0.27445
98 ->105	-0.18929
98 ->106	-0.16296
 Excited State 58:	Singlet-A
87 ->101	0.55013
96 ->105	0.19339
96 ->106	-0.10759
97 ->105	0.15066
97 ->106	0.16780
98 ->105	0.12178
98 ->106	0.10983
100 ->112	-0.10651
 Excited State 59:	Singlet-A
88 ->102	-0.10251
89 ->103	0.17405
90 ->103	-0.27249
99 ->107	0.39601
99 ->109	-0.36885
 Excited State 60:	Singlet-A
89 ->103	-0.15728

90 ->103	0.42710	
94 ->104	0.17058	
99 ->107	0.44974	
 Excited State 61:	Singlet-A	6.0646 eV 204.44 nm f=0.0082 <S**2>=0.000
90 ->103	-0.16012	
91 ->104	0.46102	
92 ->104	-0.43566	
93 ->104	-0.17743	
94 ->104	0.14146	
 Excited State 62:	Singlet-A	6.0693 eV 204.28 nm f=0.0185 <S**2>=0.000
88 ->102	0.16896	
89 ->103	0.10116	
90 ->103	-0.20485	
94 ->104	-0.15163	
99 ->107	0.32961	
99 ->109	0.47674	
 Excited State 63:	Singlet-A	6.0859 eV 203.72 nm f=0.0013 <S**2>=0.000
87 ->103	-0.15653	
88 ->102	0.58160	
88 ->103	0.12005	
89 ->103	0.12973	
99 ->109	-0.19751	
 Excited State 64:	Singlet-A	6.1514 eV 201.55 nm f=0.0540 <S**2>=0.000
88 ->102	0.10394	
88 ->104	0.10565	
89 ->103	0.17692	
90 ->103	-0.15908	
93 ->103	-0.11071	
93 ->104	0.32139	
94 ->104	0.45996	
97 ->108	0.11916	
98 ->108	-0.11085	
 Excited State 65:	Singlet-A	6.1755 eV 200.77 nm f=0.0422 <S**2>=0.000
87 ->102	0.24021	
88 ->101	0.14780	
88 ->103	-0.12277	
97 ->108	-0.22738	
98 ->108	0.28916	
100 ->111	-0.20123	
100 ->112	0.22601	
100 ->113	0.27846	
 Excited State 66:	Singlet-A	6.2229 eV 199.24 nm f=0.0016 <S**2>=0.000
97 ->108	0.47586	
98 ->108	0.46357	
100 ->113	-0.10189	
 Excited State 67:	Singlet-A	6.2317 eV 198.96 nm f=0.0234 <S**2>=0.000
87 ->102	0.12927	
88 ->101	0.12253	
90 ->107	-0.16073	
93 ->104	-0.14959	
95 ->107	0.42096	
96 ->107	0.10566	
97 ->107	-0.16993	
98 ->107	-0.17074	
100 ->113	-0.32159	
 Excited State 68:	Singlet-A	6.2327 eV 198.93 nm f=0.0436 <S**2>=0.000
87 ->102	-0.18113	
88 ->101	-0.14959	
88 ->103	0.13527	
90 ->107	-0.12013	
93 ->104	0.20511	
95 ->107	0.30559	
97 ->107	-0.12693	

97 ->108	0.11271			
98 ->107	-0.11730			
98 ->108	0.12107			
98 ->109	0.10473			
100 ->113	0.38144			
Excited State 69:	Singlet-A	6.2551 eV	198.21 nm	f=0.0464 <S**2>=0.000
87 ->102	0.13099			
88 ->101	0.15533			
88 ->103	-0.10766			
93 ->104	-0.20293			
97 ->108	0.20241			
97 ->109	-0.12149			
98 ->108	-0.12796			
98 ->109	0.41097			
100 ->111	0.10498			
100 ->113	0.23365			
Excited State 70:	Singlet-A	6.2728 eV	197.65 nm	f=0.0057 <S**2>=0.000
87 ->103	0.40520			
93 ->104	-0.16079			
97 ->109	0.32938			
98 ->109	-0.22693			
100 ->113	0.17203			
Excited State 71:	Singlet-A	6.2838 eV	197.31 nm	f=0.0113 <S**2>=0.000
93 ->104	0.13071			
95 ->107	-0.21028			
96 ->106	-0.12837			
97 ->107	-0.22090			
97 ->109	0.41465			
98 ->107	-0.15137			
98 ->109	0.25147			
100 ->113	-0.12965			
Excited State 72:	Singlet-A	6.2903 eV	197.10 nm	f=0.0198 <S**2>=0.000
87 ->102	-0.15283			
87 ->103	0.40612			
88 ->102	0.15304			
95 ->105	-0.18606			
97 ->109	-0.19104			
98 ->109	0.26695			
99 ->110	-0.10833			
100 ->113	-0.20821			
SavETr: write IOETrn= 770 NScale= 10 NData= 16 NLR=1 NState= 72 LETran= 1306.				